

SWITCHING DIODE

FEATURES

- Very Small Plastic Package
- High Switching Speed

APPLICATIONS

• High-Speed Switching in e.g. Surface Mounted Circuits

MARKING: A6





MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit		
V _{RRM}	Peak Repetitive Reverse Voltage	100	V		
V _R	DC Blocking Voltage	100			
lo	Continuous Forward Current	250	mA		
I _{FSM}	Non-repetitive Peak Forward SurgeCurrent@t=8.3ms	2.0	A		
PD	Power Dissipation	250	mW		
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	500	°C/W		
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C		

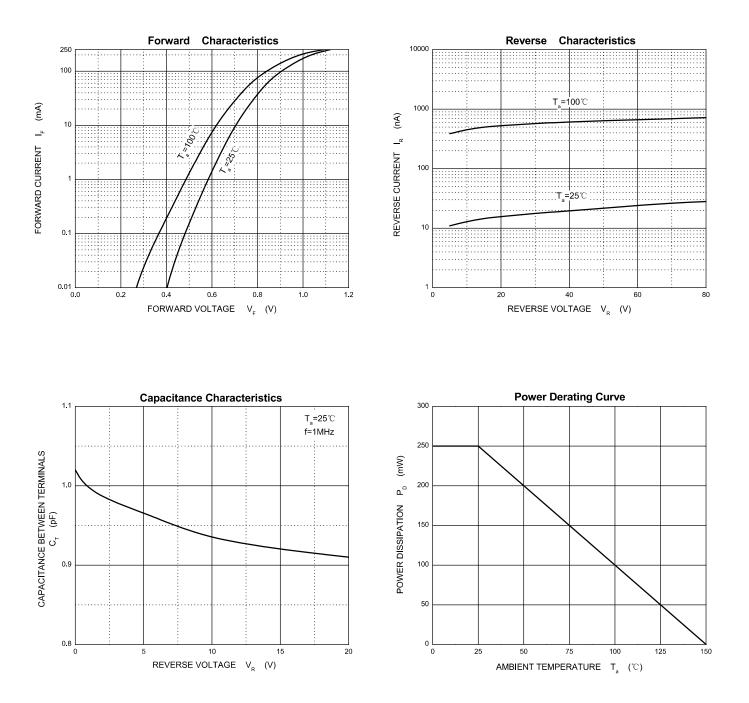
ELECTRICAL CHARACTERISTICS(T_a=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Reverse voltage	V _(BR)	Ι _R =100μΑ	100			V
Reverse current	I _R	V _R =25V			30	nA
Reverse current		V _R =75V			1	μA
	VF	I _F =1mA			0.715	V
		I _F =10mA			0.855	
Forward voltage		I _F =50mA			1	
		I _F =150mA			1.25	
Total capacitance	C _{tot}	V _R =0V,f=1MHz			1.5	pF
Reverse recovery time	t _{rr}	$I_F = I_R = 10 \text{mA}, I_r = 0.1 \times I_R$			4	ns



BAS16HT1G SWITCHING DIODE

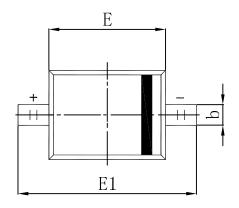
Typical Characteristics

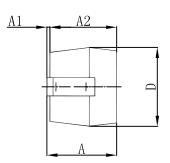


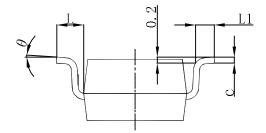


SWITCHING DIODE

SOD-323 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А		1.100		0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.800	1.000	0.031	0.039	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
Е	1.600	1.800	0.063	0.071	
E1	2.500	2.750	0.098	0.108	
L	0.475 REF		0.019 REF		
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	